

MT53E256M32D2DS-046 AAT:B TR

MT53E256M32D2DS-046 AAT:B TR Information

Heisener.com	 MT53E256M32D2DS-046 AAT:B TR Micron Technology Inc. Integrated Circuits (ICs) Memory IC DRAM LPDDR4 WFBGA - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MT53E256M32D2DS-046 AAT:B TR Specifications

Manufacturer Part Number	MT53E256M32D2DS-046 AAT:B TR
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Volatile
Memory Format	DRAM
Technology	SDRAM - Mobile LPDDR4
Memory Size	8Gb (256M x 32)
Memory Interface	-
Clock Frequency	2.133GHz
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	0.6V, 1.1V
Operating Temperature	-40°C ~ 105°C
Mounting Type	Surface Mount
Package / Case	-
Supplier Device Package	-
	Report errors?

MT53E256M32D2DS-046 AAT:B TR Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MT53E256M32D2DS-046 AAT:B TR Payment Methods





If you have any question about MT53E256M32D2DS-046 AAT:B TR, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com